

产品规格书

Specifcation of products

产品名称: 快恢复二极管

产品型号: MURP500100CI

浙江世菱半导体有限公司
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Ultra-Fast Soft Recovery Diode Module

MURP500100CI

Description

Ultra-FRD module devices are optimized to reduce losses and EMI/RFI in high frequency power conditioning electrical systems. These diode modules are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

Features

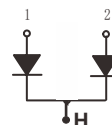
- ☞ Repetitive Reverse Voltage : $V_{RRM} = 100V$
- ☞ Low Forward Voltage Drop : $V_F (typ.) = 1.0V$
- ☞ Average Forward Current : $I_F (AV.) = 500A @ T_c = 100^\circ C$
- ☞ Ultra-Fast Reverse RecoveryTime : $t_{rr} (typ.) = 95 ns$
- ☞ Extensive Characterization of RecoveryParameters
- ☞ Reduced EMI and RFI
- ☞ Non IsolationType Package

Applications

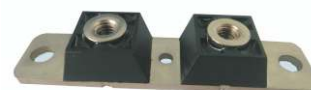
Motor Drives, Free wheel use, High Power Converters, Welders, Various Switching and Telecommunication Power Supply

Equivalent Circuit and Package

Equivalent Circuit



Package



Please see the package Out line information

Absolute Maximum Ratings @ $T_j = 25^\circ C$ (PerLeg)

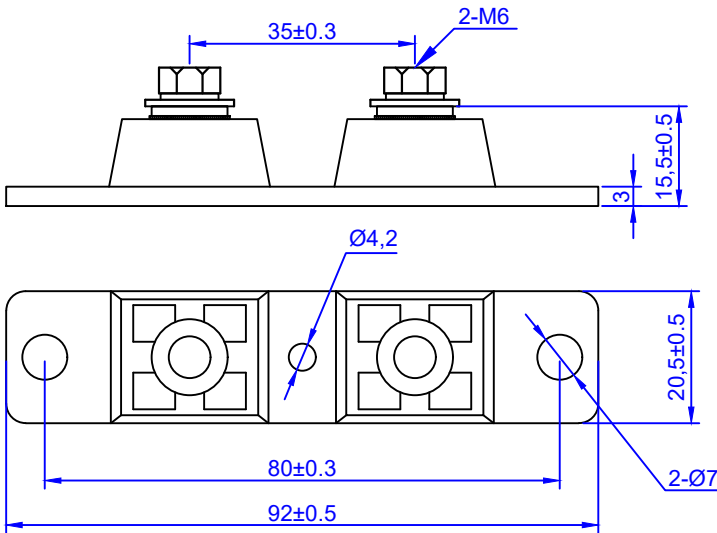
Symbol	Parameter	Conditions	Ratings	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		100	V
$V_R (DC)$	Reverse DC Voltage		100	V
$I_F (AV)$	Average Forward Current @ $T_c = 25^\circ C$ @ $T_c = 100^\circ C$	Resistive Load	500 420	A A
I_{FSM}	Surge (non-repetitive) Forward Current	One Half Cycle at 60Hz, Peak Value	4600	A
I^2_t	I^2_t for Fusing	Value for One Cycle Current, $t_W = 8.3ms, T_j = 25^\circ C$ Start	$56.4 * 10^3$	$A^2 s$
T_j	Junction Temperature		$-40 \sim 125$	$^\circ C$
T_{stg}	Storage Temperature		$-40 \sim 125$	$^\circ C$
P_d	Maximum Power Dissipation		820	W
—	Mounting Torque		4.0	N.m
—	Terminal Torque		3.0	N.m

Thermal Characteristics

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal Resistance	Junction to Case	-	-	0.22	°C/W

Electrical Characteristics@T_j=25°C (unless otherwise specified)

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
V_R	Cathode Anode Breakdown Voltage	$I_R = 100\mu A$	100	-	-	V
V_{FM}	Maximum Forward Voltage	$I_{FM} = 300A, T_c = 25^\circ C$	-	1.0	1.1	V
		$I_{FM} = 300A, T_c = 100^\circ C$	-	0.8	1.0	V
I_{RRM}	Repetitive Peak Reverse Current	$T_c = 100^\circ C, V_{RRM}$ applied	-	-	5.0	mA
t_{rr}	Reverse Recovery Time	$I_{FM} = 300A, V_R = 100V, di/dt = -100A/\mu s, T_c = 25^\circ C$	-	95	100	ns
		$T_c = 100^\circ C$	-	180	-	ns



Rating and Characteristic

Performance Curves

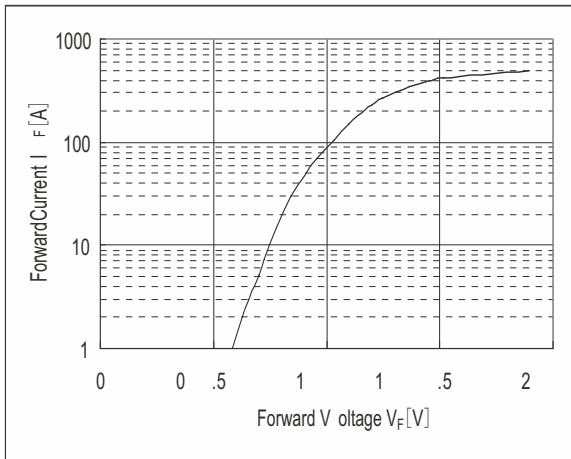


Fig. 1 : Typical Forward Voltage Drop vs. Instantaneous Forward Current

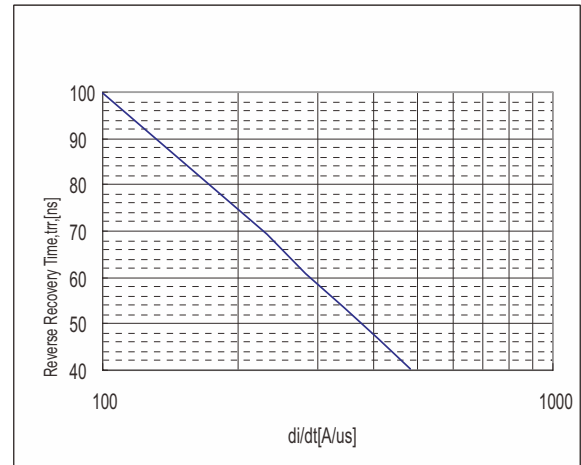


Fig. 2 : Typical Reverse Recovery Time vs. $-di/dt$

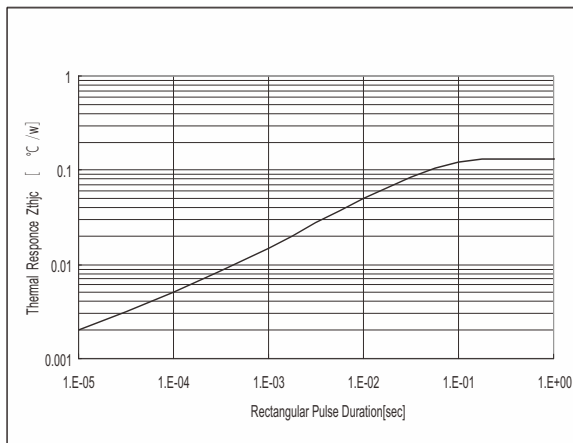


Fig. 3 : Transient Thermal Impedance (Z_{thjc}) Characteristics

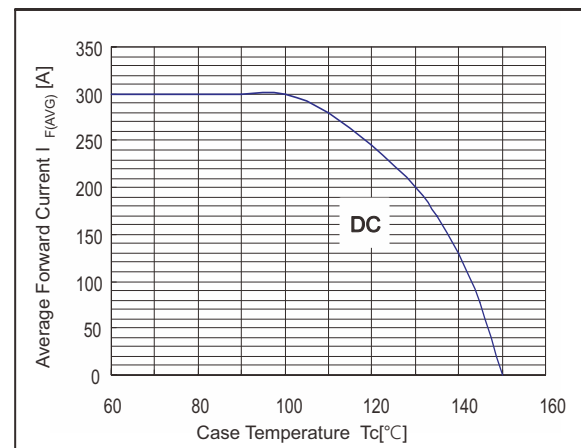


Fig. 4 : Forward Current Derating Curve